

L Number	Hits	S arch Text	DB	Time stamp
-	7342	(p wer adj (supply s urc)) n ar11 di de near11 (switch transist r)	USPAT	2003/12/14 23:06
-	871	(307/87).CCLS.	USPAT	2003/12/14 23:03
-	12	(power adj (supply source)) near11 (diode\$1or or\$1diode diode\$1oring)	USPAT	2003/12/14 23:16
-	47	diode\$1or or\$1diode diode\$1oring	USPAT	2003/12/14 23:27
-	6	("4857985" "5109162" "5517379" "5654858" "5654859" "6084790").PN.	USPAT	2003/12/14 23:20
-	153	(voltage) near11 present near11 (gate base) near11 (transistor fet bjt)	USPAT	2003/12/14 23:24
-	7580	diode near11 first near11 (source)	USPAT	2003/12/14 23:24
-	7319	diode near11 second near11 (source)	USPAT	2003/12/14 23:24
-	4421	(diode near11 first near11 (source)) same (diode near11 second near11 (source))	USPAT	2003/12/14 23:24
-	1849	((diode near11 first near11 (source)) same (diode near11 second near11 (source))) same (transistor fet bjt)	USPAT	2003/12/14 23:25
-	216	((diode near11 first near11 (source)) same (diode near11 second near11 (source))) same (transistor fet bjt) same (disconnect\$3 off disabl\$3 interrupt\$3 discontin\$3)	USPAT	2003/12/14 23:25
-	2	or\$5diode	USPAT	2003/12/14 23:28
-	68	diode\$5or diode\$5oring	USPAT	2003/12/14 23:30
-	467	((327/518) or (327/520)).CCLS.	USPAT	2003/12/14 23:33
-	20	((327/518) or (327/520)).CCLS.) and inverter	USPAT	2003/12/14 23:34
-	358	(307/130).CCLS.	USPAT	2003/12/14 23:34
-	15	((307/130).CCLS.) and ((fet transistor bjt) near11 (gate base) near11 inverter)	USPAT	2003/12/14 23:35